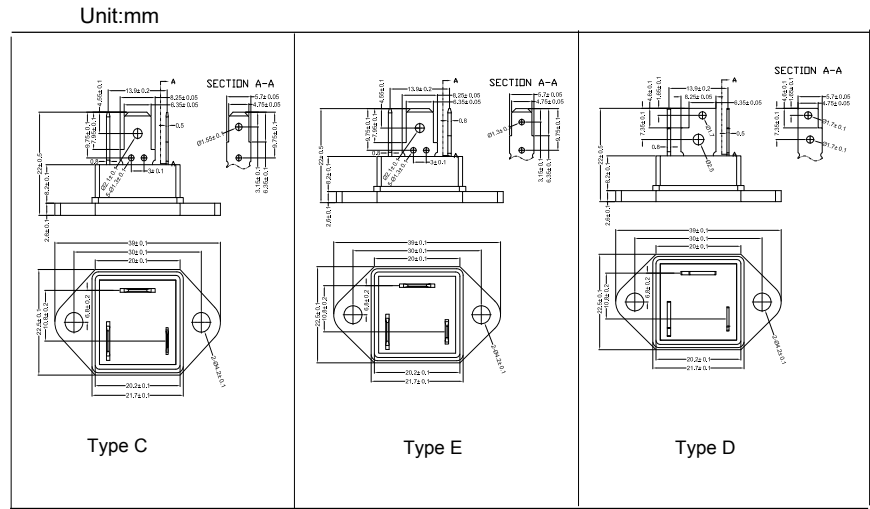


SBTA41G04B thru SBTA41G16B

Discrete Triacs (Isolated)



	VDRM/RM	VDSM/RSM
	V	V
SBTA41G04B	400	500
SBTA41G06B	600	700
SBTA41G08B	800	900
SBTA41G10B	1000	1100
SBTA41G12B	1200	1300
SBTA41G16B	1600	1700

Symbol	Test Conditions	Maximum Ratings	Unit
I_{TRMS}	$T_{VJ}=80\text{ }^{\circ}\text{C}$	40	A
I_{TSM}	$T_{VJ}=45\text{ }^{\circ}\text{C}$ $V_R=0$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	420 400	A
	$T_{VJ}=T_{VJM}$ $V_R=0$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	350 320	
I^2t	$T_{VJ}=45\text{ }^{\circ}\text{C}$ $V_R=0$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	880 850	A^2s
	$T_{VJ}=T_{VJM}$ $V_R=0$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	760 720	
$(di/dt)_{cr}$	$T_{VJ}=T_{VJM}$ $f=50\text{Hz}$, $t_p=200\mu\text{s}$ $V_D=2/3V_{DRM}$ $I_G=0.3\text{A}$ $di_G/dt=0.3\text{A}/\mu\text{s}$	repetitive, $I_T=40\text{A}$ 50	A/ μs
		non repetitive, $I_T=I_{TAVM}$ 300	
$(dv/dt)_{cr}$	$T_{VJ}=T_{VJM}$; $R_{GK}=\infty$; method 1 (linear voltage rise)	$V_{DR}=2/3V_{DRM}$ 500	V/ μs
P_{GM}	$T_{VJ}=T_{VJM}$ $I_T=I_{TAVM}$	$t_p=30\mu\text{s}$	10
		$t_p=300\mu\text{s}$	5
P_{GAV}		1	W
V_{RGM}		10	V
T_{VJ} T_{VJM} T_{stg}		-40...+125	$^{\circ}\text{C}$
		125	
		-40...+125	
V_{ISOL}	50/60Hz, RMS $t=1\text{minute}$, leads-to-tab	2500	V~
M_d	Mounting torque (M4)	0.8...1.5	Nm
Weight		25	g



SBTA41G04B thru SBTA41G16B

Discrete Triacs (Isolated)

Symbol	Test Conditions	Characteristic Values	Unit
I_R, I_D	$T_{VJ}=T_{VJM}; V_D=V_{DRM}$	10	mA
V_{TM}	$I_T=60A; T_{VJ}=25^{\circ}C$	1.44	V
V_{TO}	For power-loss calculations only ($T_{VJ}=125^{\circ}C$)	0.85	V
r_T		10	m Ω
V_{GT}	$V_D=6V; I_T=1A; T_{VJ}=25^{\circ}C$	I	1.3
		II	1.3
		III	1.3
		IV	1.5
I_{GT}	$V_D=6V; I_T=1A; T_{VJ}=25^{\circ}C$	I	50
		II	50
		III	50
		IV	100
V_{GD}	$T_{VJ}=T_{VJM}; V_D=2/3V_{DRM}$	0.2	V
I_{GD}		10	mA
I_H	$T_{VJ}=25^{\circ}C; V_D=6V; R_{GK}=\infty$	100	mA
R_{thJC}	DC current	1.3	K/W
R_{thJH}	DC current	1.5	K/W
a	Max. acceleration, 50 Hz	50	m/s ²

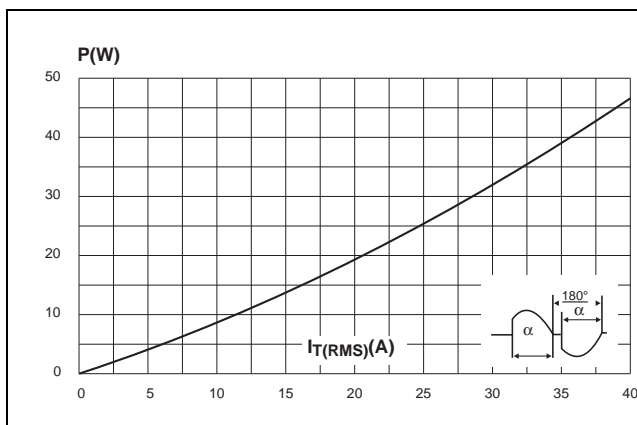


Fig.1 Maximum power dissipation versus on-state rms current (full cycle)

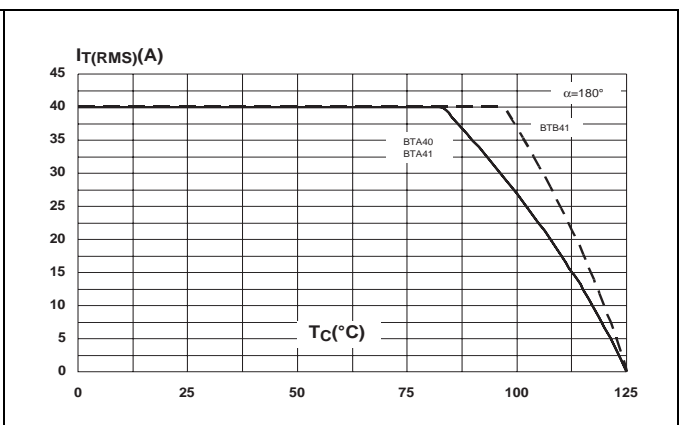


Fig.2 On-state rms current versus case temperature (full cycle)

SBTA41G04B thru SBTA41G16B

Discrete Triacs (Isolated)

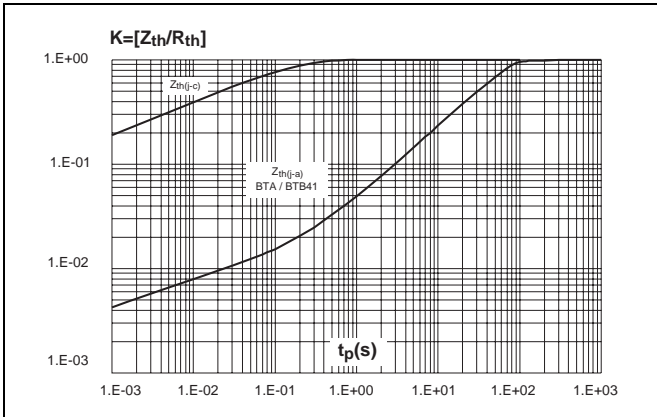


Fig.3 Relative variation of thermal impedance versus pulse duration

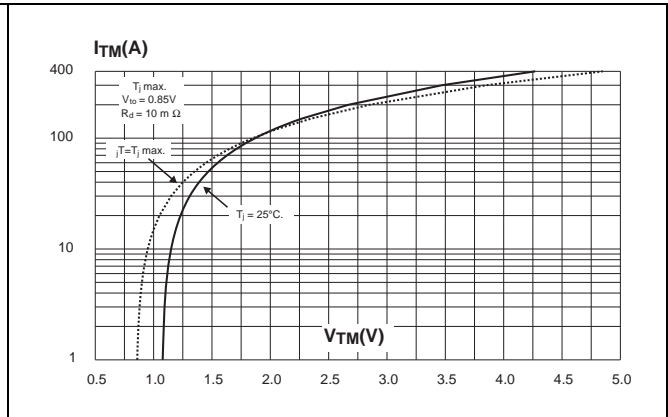


Fig.4 On-state characteristics (maximum values)

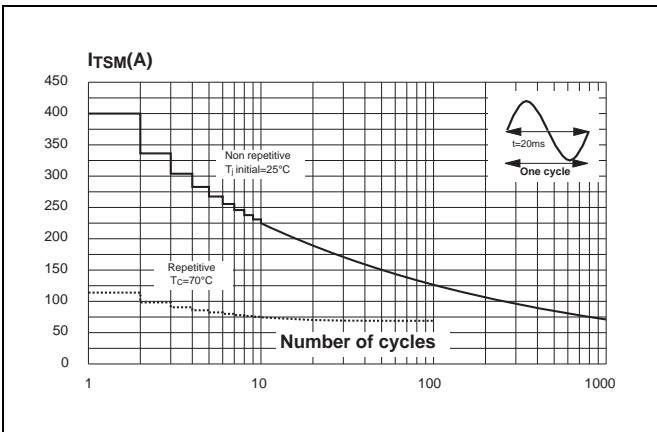


Fig.5 Surge peak on-state current versus number of cycles

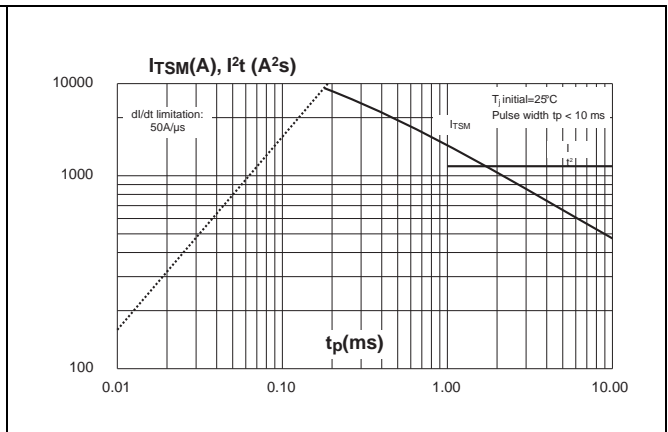


Fig.6 Non-repetitive surge peak on-state current for a sinusoidal pulse and corresponding value of I^2t

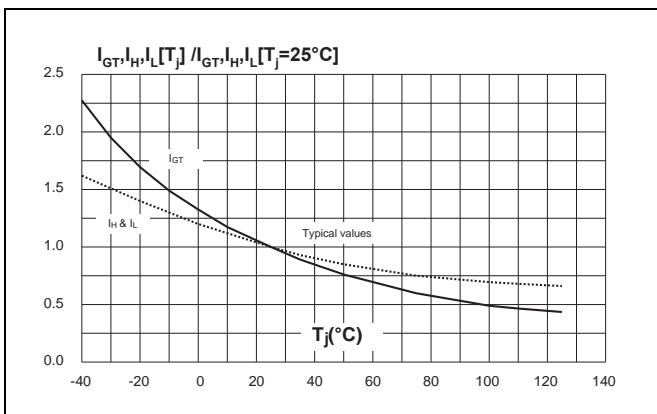


Fig.7 Relative variation of gate trigger, holding and latching current versus junction temperature

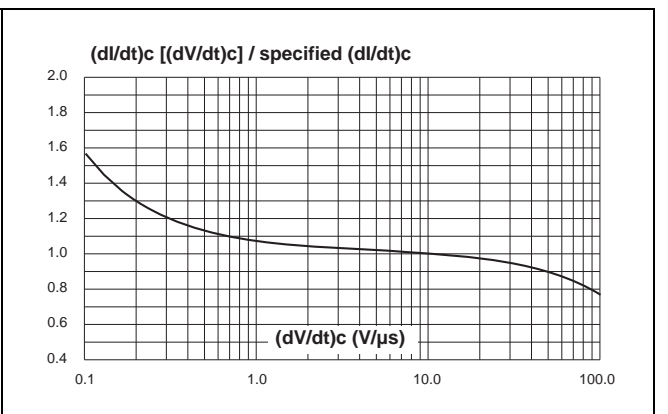


Fig.8 Relative variation of critical rate of decrease of main current versus $(dV/dt)_c$ (typical values)